L Number	Hits	Search Text	DB	Time stamp
1	1601	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 13:56
2	1593	349/149-152.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 13:57
3	461	349/149-152.ccls. and ((contact adj hole) opening)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 13:58
4	203	349/149-152.ccls. and ((contact adj hole) opening) and input	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 13:58
5	1225	349/43 and ((contact adj hole) opening)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 13:59
6	71	349/43 and 349/149-152.ccls. and ((contact adj hole) opening)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 15:58
7	7338	pixel near10 ((contact adj hole) opening)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 15:58
8	2311	(pixel near10 ((contact adj hole) opening)) and 349/.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 15:59
9	50	(pixel near10 ((contact adj hole) opening)) and 349/43 and 349/149-152.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 16:01
11	64	(pixel near10 ((contact adj hole) opening)) and (input adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/04 16:01
-	1199	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 16:59
-	1340	349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:00
-	1346	349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:00
-	239	349/114	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:05

-	100	349/159	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:05
-	168	349/162	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:05
-	233	345/80	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:06
-	805	345/90	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:07
-	3682313	(line or LOG)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:09
-	95863	(line or LOG) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:10
-	59030	(line or LOG) and (liquid adj crystal) and driv$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:10
-	0	(line or LOG) and (liquid adj crystal) and driv$4 and (double-layer) and (AlNd adj alloy)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:12
-	85	(line or LOG) and (liquid adj crystal) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:12
-	50	(line or LOG) and (liquid adj crystal) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo) and Cr	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:13
-	78	(line or LOG) and (liquid adj crystal) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum) and (Cr or chromium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:16
-	2	(line or LOG) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum) and (Cr or chromium) and 349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:18
-	1	(line or LOG) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum) and (Cr or chromium) and 349/113 and 349/114	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:18
-	1120	(line or LOG) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum) and (Cr or chromium) and 349/113 or transflect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:19

-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/113 and transflect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:19
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/159	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:20
-	2	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/162	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 345/32	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 345/80	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 345/90	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	525	345/32	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	7	(line or LOG) and (line with resistance) and (drive$4 with retard$4) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:26
-	99	349/113 and 349/114	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 17:27
-	252	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 14:35
-	183	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and insulat$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 18:03
-	38	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and insulat$ and (line with resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 17:31
-	24	349/113 and 349/114 and (Cr or chromium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 17:29
-	8	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 18:03

-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and ((gate adj line)and (data adj line) and (reflective adj electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 18:18
-	107	(line or LOG)and ((gate adj line)and (data adj line) and (reflective adj electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 14:33
-	35562	(choo or chung).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 14:34
-	7174	(choo or chung).in.	USPAT	2003/08/14 14:34
-	216	(choo or chung).in. and (liquid adj crystal)	USPAT	2003/08/14 14:35
-	5	(choo or chung).in. and (liquid adj crystal) and transflect$4 and reflect$4	USPAT	2003/08/14 15:22
-	1	6466280.pn.	USPAT	2003/08/14 15:22
-	18	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 15:25
-	9	(pixel near10 (contact adj hole)) near10 (drain and gate and reflect$4)and (liquid adj crystal)	USPAT; US-PGPUB; JPO	2004/03/18 10:44
-	9	(pixel near10 (contact adj hole)) near10 (drain and gate and reflect$4)	USPAT; US-PGPUB; JPO	2004/03/18 11:19
-	13	(pixel with (drain and gate and reflect$4)) near10 (contact adj hole$4)	USPAT; US-PGPUB; JPO	2004/03/18 11:41
-	44	(pixel and (drain and gate and reflect$4)) near10 (contact adj hole$4)	USPAT; US-PGPUB; JPO	2004/03/18 11:41
-	113	(line or LOG)and (liquid adj crystal) and (line near10 signal near10 driv$4) and (double-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 16:41
-	17112	(choo chung park).in.	USPAT	2004/08/02 16:42
-	735	(choo chung park).in. and (liquid adj crystal)	USPAT	2004/08/02 16:43
-	543	(choo chung park).in. and (liquid adj crystal)and (line near "10" structure)	USPAT	2004/08/02 16:44
-	477	(choo chung park).in. and (liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)	USPAT	2004/08/02 16:45
-	20814	(liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive	USPAT	2004/08/02 16:46
-	121	(liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive and (refelct$4 transflect$4)	USPAT	2004/08/02 16:47
-	132	(choo chung park).in. and (liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive	USPAT	2004/08/02 16:51
-	329	(liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive and (refelct$4 transflect$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 16:48
-	280	(liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive and (refelct$4 transflect$4)and pixel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 16:48

-	44	(liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive and (refelct$4 transflect$4)and pixel and passivation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 16:48
-	23	(choo chung park).in. and (liquid adj crystal)and (line near "10" structure)and ((line on glass) LOG)and drive and LG.as.	USPAT	2004/08/02 16:51
-	13	(liquid adj crystal)and (line near10 structure)and ((line on glass) LOG)and drive and (refelct$4 transflect$4)and pixel and passivation and (contact adj hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 17:20
-	25	(liquid adj crystal)and drive and (refelct$4 transflect$4)and pixel and passivation and (contact adj hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 17:15
-	1	6466280.pn.	USPAT	2004/08/02 17:15
-	58	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and insulat$ and (line with resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/02 17:32
-	52	((input adj line) near10 (first and second and third)) and 345/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/03 08:59
-	6	((input adj line) near10 (first and second and third)) and 349/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/03 09:01
-	65	((input adj line) and (first and second and third)) and 349/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/03 09:24
-	18	((input adj line) and (first and second and third)) and 349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/03 09:24
-	12	((input adj line) and (first and second and third)) and 349/152	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/03 09:26